

BIPOLAR TRANSISTOR, NPN, 40V, Transistor Polarity:NPN, Collector Emitter Voltage V(br)ceo:40V, Transition Frequency ft:250MHz, Power Dissipation Pd:150mW, DC Collector Current:600mA, DC Current Gain hFE:100hFE

Manufacturers	<a href="#">ON Semiconductor, LLC</a>
Package/Case	SC-70-3
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for MMBT4401WT1G or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.



## General Description

The NPN Bipolar Transistor is designed for general purpose amplifier applications. It is housed in the SOT-323/SC-70 package, which is designed for low power surface mount applications.

## Features

Moisture Sensitivity Level: 1

ESD Rating: Human Body Model - 4 kV Machine Model - 400 V

Pb-Free Package is Available

## Application

ONSEMI

## Related Products



### [MMPQ6700](#)

ON Semiconductor, LLC  
SOIC-16



### [MMPQ2907A](#)

ON Semiconductor, LLC  
SOP-16



### [MMBT2222AWT3G](#)

ON Semiconductor, LLC  
SC-70



### [MMPQ3906](#)

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[MMPQ3904](#)

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